

MC100EPT22

Dual LVTTTL/LVCMOS to Differential LVPECL Translator

The MC100EPT22 is a dual LVTTTL/LVCMOS to differential LVPECL translator. Because LVPECL (Positive ECL) levels are used only +3.3V and ground are required. The small outline 8-lead SOIC package and the single gate of the EPT22 makes it ideal for those applications where space, performance, and low power are at a premium. Because the mature MOSAIC 5 process is used, low cost and high speed can be added to the list of features.

- 420ps Typical Propagation Delay
- Differential LVPECL Outputs
- Small Outline SOIC Package
- PNP LVTTTL Inputs for Minimal Loading
- Flow Through Pinouts
- Q Output will default HIGH with inputs open
- ESD Protection: 4.0 KV HBM, 200 V MM
- Maximum Frequency > 1.1 GHz
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8",
Oxygen Index 28 to 34
- Transistor Count = 164 devices

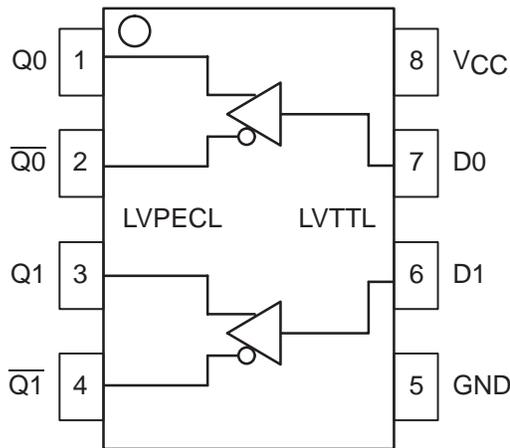
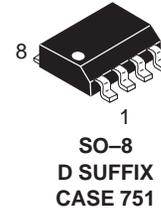


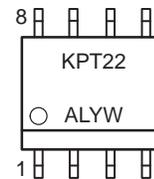
Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



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MARKING DIAGRAM



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

*For additional information, see Application Note AND8002/D

PIN DESCRIPTION

PIN	FUNCTION
Q0, Q1, Q0-bar, Q1-bar	Diff. LVPECL Outputs
D0, D1	LVTTTL Inputs
VCC	Positive Supply
GND	Ground

ORDERING INFORMATION

Device	Package	Shipping
MC100EPT22D	SOIC	98 Units/Rail
MC100EPT22DR2	SOIC	2500 Tape & Reel

MC100EPT22

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	Power Supply	6.0 to 0	VDC
V_I	Input Voltage (V_I not more positive than V_{CC})	6.0 to 0	VDC
I_{out}	Output Current Continuous Surge	50 100	mA
T_A	Operating Temperature Range	-40 to +85	°C
T_{stg}	Storage Temperature	-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient) Still Air 500lfpm	190 130	°C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	41 to 44 ± 5%	°C/W
T_{sol}	Solder Temperature (<2 to 3 Seconds: 245°C desired)	265	°C

* Maximum Ratings are those values beyond which damage to the device may occur.

LVTTTL INPUT DC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V; $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Symbol	Characteristic	Min	Typ	Max	Unit
I_{IH}	Input HIGH Current ($V_{in} = 2.7V$)			20	μA
I_{IHH}	Input HIGH Current MAX ($V_{in} = 6.0V$)			100	μA
I_{IL}	Input LOW Current ($V_{in} = 0.5V$)			-0.6	mA
V_{IK}	Input Clamp Voltage ($I_{in} = -18\text{mA}$)			-1.0	V
V_{IH}	Input HIGH Voltage	2.0			V
V_{IL}	Input LOW Voltage			0.8	V

LVPECL OUTPUT DC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$, GND = 0V) (Note 3.)

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{CC}	Power Supply Current HIGH (Note 1.)	32	43	55	35	45	60	37	46	62	mA
V_{OH}	Output HIGH Voltage (Note 2.)	2100	2240	2400	2100	2280	2400	2100	2350	2400	mV
V_{OL}	Output LOW Voltage (Note 2.)	1350	1490	1600	1350	1555	1600	1350	1550	1600	mV

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

1. $V_{CC} = 3.3V$, GND = 0V, all other pins floating.
2. All loading with 50 ohms to V_{CC} -2.0 volts.
3. Output parameters vary 1:1 with V_{CC} .

AC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V)

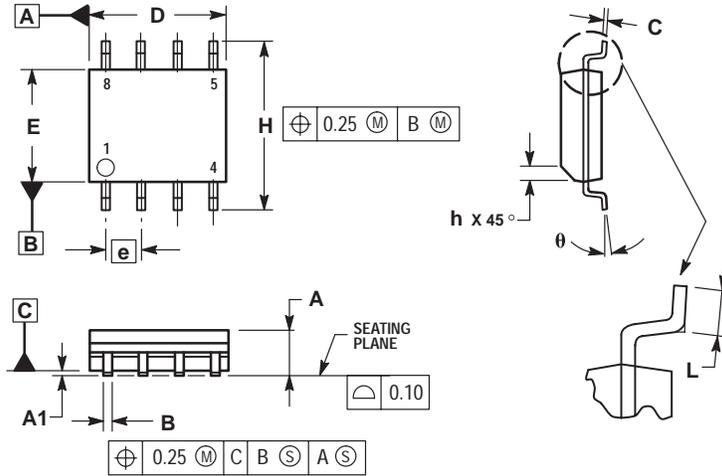
Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f_{max}	Maximum Toggle Frequency (Note 4.)	0.8	1.1		0.8	1.1		0.8	1.1		GHz
t_{PLH} , t_{PHL}	Propagation Delay to Output Differential	250	400	650	250	420	675	300	500	700	ps
t_{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t_r & t_f	Output Rise/Fall Times (20% – 80%) Q, \bar{Q}	50	110	200	60	120	220	70	140	250	ps

4. F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.

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PACKAGE DIMENSIONS

SO-8
D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751-06
ISSUE T



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS ARE IN MILLIMETER.
3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.35	0.49
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.25
θ	0°	7°

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